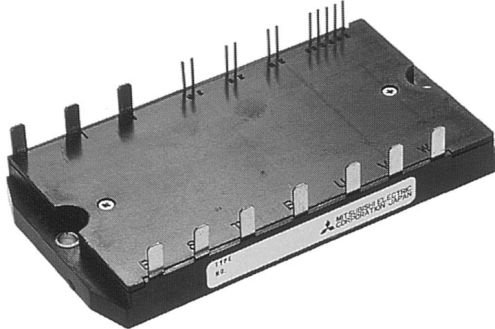


CM30MD3-12H

**MEDIUM POWER SWITCHING USE
FLAT-BASE TYPE, INSULATED TYPE**

CM30MD3-12H



- IC 30A
- VCES 600V
- Insulated Type
- CIB Module
 - 3 ϕ Inverter+1 ϕ Converter
- UL Recognized

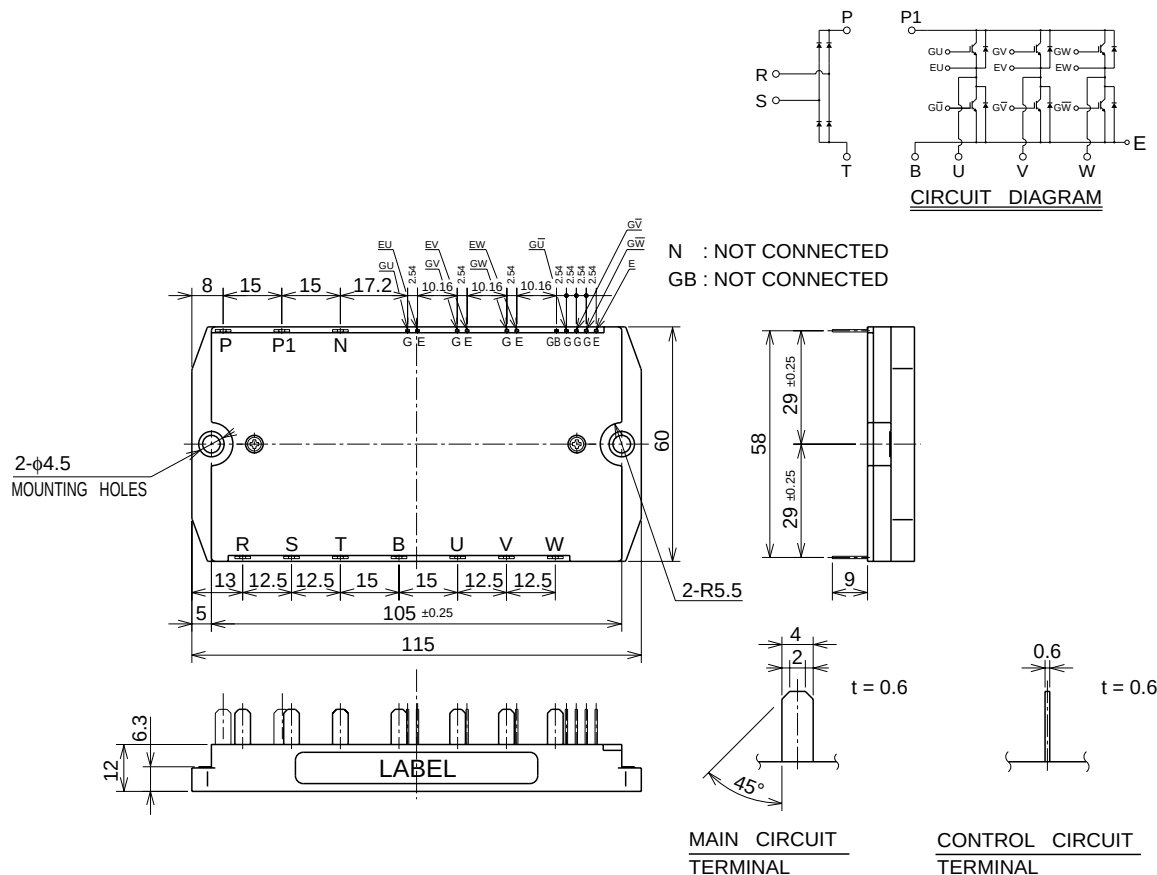
Yellow Card No. E80276 (N)
File No. E80271

APPLICATION

AC & DC motor controls, General purpose inverters, Servo controls, NC, Robotics, UPS

OUTLINE DRAWING & CIRCUIT DIAGRAM

Dimensions in mm



CM30MD3-12H

MEDIUM POWER SWITCHING USE
FLAT-BASE TYPE, INSULATED TYPE

MAXIMUM RATINGS (T_j = 25°C) INVERTER PART

Symbol	Parameter	Condition	Rating	Unit
V _{CES}	Collector-emitter voltage	G – E Short	600	V
V _{GES}	Gate-emitter voltage	C – E Short	±20	V
I _C	Collector Current	T _c = 25°C	30	A
I _{CM}		PULSE (Note. 2)	60	A
I _E (Note. 1)	Emitter Current	T _c = 25°C	30	A
I _{EM} (Note. 1)		PULSE (Note. 2)	60	A
P _C (Note. 3)	Maximum collector dissipation	T _f = 25°C	66	W

CONVERTER PART

Symbol	Parameter	Condition	Rating	Unit
V _{RRM}	Repetitive peak reverse voltage		800	V
E _a	Recommended AC input voltage		220	V
I _O	DC output current	1φ rectifying circuit T _f = 111°C	25	A
I _{FSM}	Surge (non-repetitive) forward current	1 cycle at 60Hz, peak value Non-repetitive	550	A
I ² _t	I ² _t for fusing	Value for one cycle of surge current	1.2X10 ³	A ² s

COMMON RATING

Symbol	Parameter	Condition	Rating	Unit
T _j	Junction temperature		–40 ~ +150	°C
T _{stg}	Storage temperature		–40 ~ +125	°C
V _{iso}	Isolation voltage	AC 1 min.	2500	V
—	Mounting torque	Mounting M4 screw	0.98 ~1.47	N·m
—	Weight	Typical value	100	g

CM30MD3-12H

MEDIUM POWER SWITCHING USE
FLAT-BASE TYPE, INSULATED TYPE

ELECTRICAL CHARACTERISTICS (T_j = 25°C)

INVERTER PART

Symbol	Parameter	Test conditions	Limits			Unit
			Min.	Typ.	Max.	
ICES	Collector cutoff current	VCE = VCES, VGE = 0V	—	—	1	mA
VGE(th)	Gate-emitter threshold voltage	IC = 3mA, VCE = 10V	4.5	6	7.5	V
IGES	Gate-emitter cutoff current	VGE = VGES, VCE = 0V	—	—	0.5	μA
VCE(sat)	Collector-emitter saturation voltage	T _j = 25°C	—	2.1	2.8	V
		T _j = 150°C	—	2.15	—	
Cies	Input capacitance	VCE = 10V VGE = 0V	—	—	3.0	nF
Coēs	Output capacitance		—	—	2.4	nF
Cres	Reverse transfer capacitance		—	—	0.6	nF
QG	Total gate charge	VCC = 300V, IC = 30A, VGE = 15V	—	90	—	nC
td (on)	Turn-on delay time	VCC = 300V, IC = 30A	—	—	120	ns
tr	Turn-on rise time	VGE1 = VGE2 = 15V	—	—	300	ns
td (off)	Turn-off delay time	RG = 21Ω	—	—	200	ns
tf	Turn-off fall time	Resistive load	—	—	300	ns
VEC (Note. 1)	Emitter-collector voltage	IE = 30A, VGE = 0V	—	—	2.8	V
trr (Note. 1)	Reverse recovery time	IE = 30A, VGE = 0V	—	—	110	ns
Qrr (Note. 1)	Reverse recovery charge	die / dt = - 60A / μs	—	0.08	—	μC
Rth(j-Q) (Note. 5)	Thermal resistance	IGBT part, Per 1/6 module	—	—	1.9	°C/W
Rth(j-R) (Note. 5)		FWDi part, Per 1/6 module	—	—	2.4	°C/W

CONVERTER PART

Symbol	Parameter	Condition	Limits			Unit
			Min.	Typ.	Max.	
IRRM	Repetitive reverse current	VR = VRRM, T _j = 150°C	—	—	8	mA
VFM	Forward voltage drop	IF = 40A	—	—	1.6	V
Rth(j-I) (Note. 5)	Thermal resistance	Per 1/4 module	—	—	1.7	°C/W

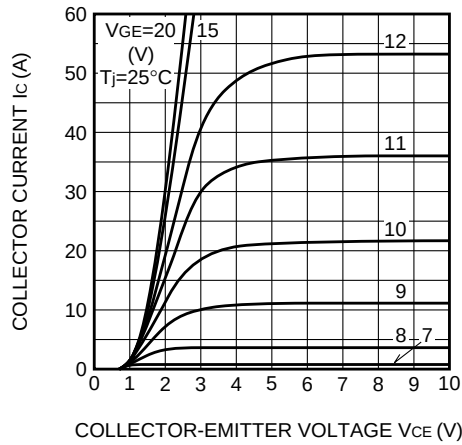
- Note 1. IE, VEC, trr, Qrr & die/dt represent characteristics of the anti-parallel, emitter to collector free-wheel diode.
2. Pulse width and repetition rate should be such that the device junction temp. (T_j) does not exceed T_{jmax} rating.
3. Junction temperature (T_j) should not increase beyond 150°C.
4. Pulse width and repetition rate should be such as to cause negligible temperature rise.
5. Thermal resistance is specified under following conditions.
• The conductive grease applied, between module and fin.
• Al plate is used as fin.

CM30MD3-12H

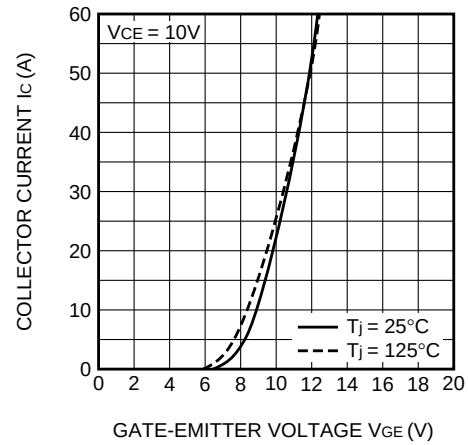
MEDIUM POWER SWITCHING USE
FLAT-BASE TYPE, INSULATED TYPE

PERFORMANCE CURVES

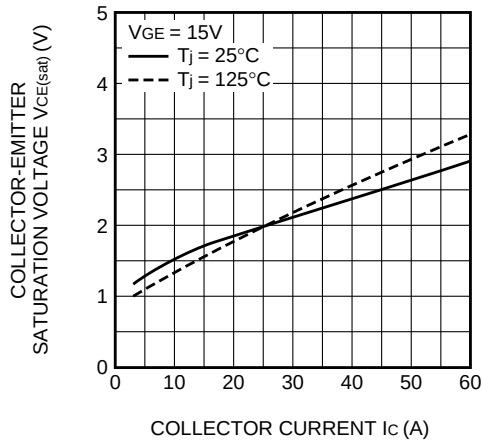
OUTPUT CHARACTERISTICS
(TYPICAL)



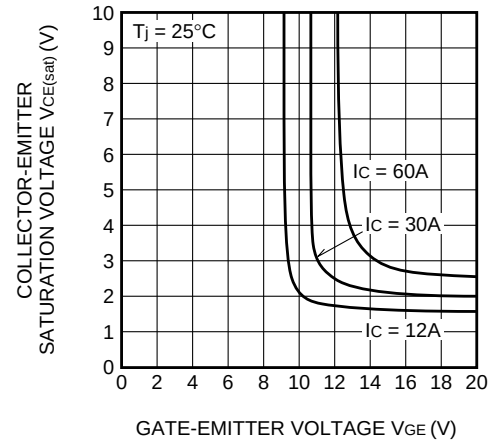
TRANSFER CHARACTERISTICS
(TYPICAL)



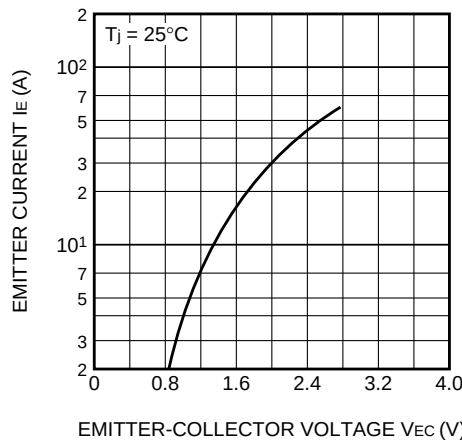
COLLECTOR-EMITTER SATURATION
VOLTAGE CHARACTERISTICS
(TYPICAL)



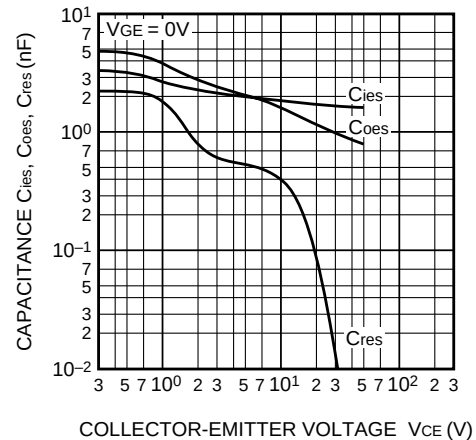
COLLECTOR-EMITTER SATURATION
VOLTAGE CHARACTERISTICS
(TYPICAL)



FREE-WHEEL DIODE
FORWARD CHARACTERISTICS
(TYPICAL)



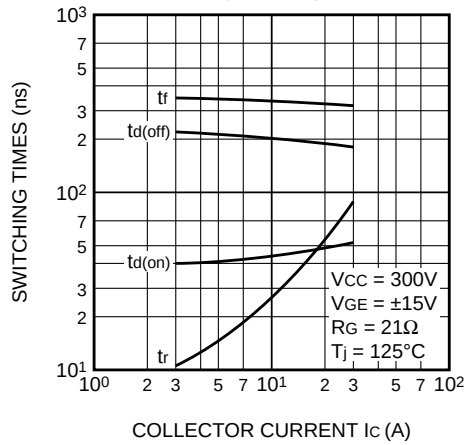
CAPACITANCE VS. V_{ce}
(TYPICAL)



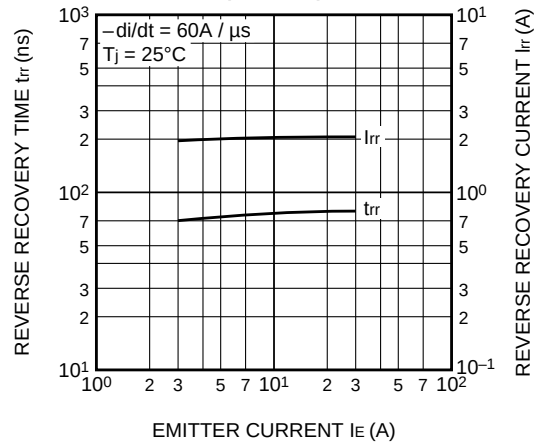
CM30MD3-12H

MEDIUM POWER SWITCHING USE
FLAT-BASE TYPE, INSULATED TYPE

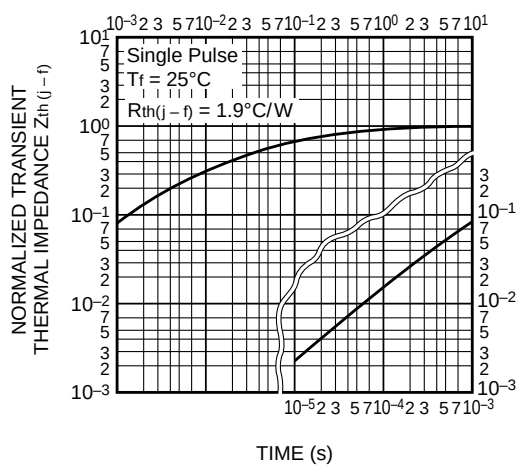
HALF-BRIDGE
SWITCHING CHARACTERISTICS
(TYPICAL)



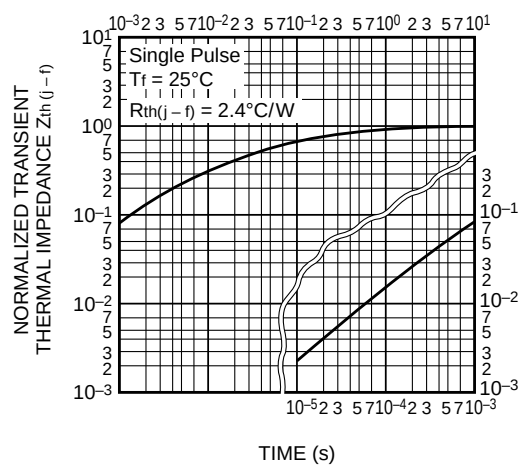
REVERSE RECOVERY CHARACTERISTICS
OF FREE-WHEEL DIODE
(TYPICAL)



TRANSIENT THERMAL
IMPEDANCE CHARACTERISTICS
(IGBT part)



TRANSIENT THERMAL
IMPEDANCE CHARACTERISTICS
(FWDi part)



V_{GE} - GATE CHARGE
(TYPICAL)

